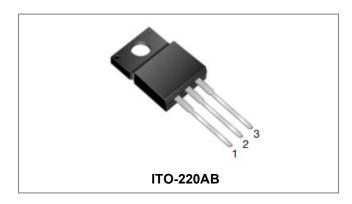






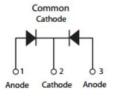
SDURF2020CT(CTR) ULTRAFAST RECTIFIER

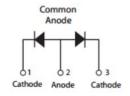


Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Circuit Diagram





SDURF2020CT

SDURF2020CTR

Features

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- · High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	200	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=100°C, rectangular wave form	10(Per Leg) 20(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	125	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ I _F = 10A, Pulse, T _J = 25°C	0.94	1.15	V
Reverse Current(Per Leg)*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25^{\circ}C$	0.3	15	μΑ
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125^{\circ}C$	50	250	μΑ
Reverse Recovery Time(Per Leg)	t _{rr1}	I _F =500mA, I _R =1A,and I _m =250mA	32	35	ns

^{*} Pulse width < 300 µs, duty cycle < 2%

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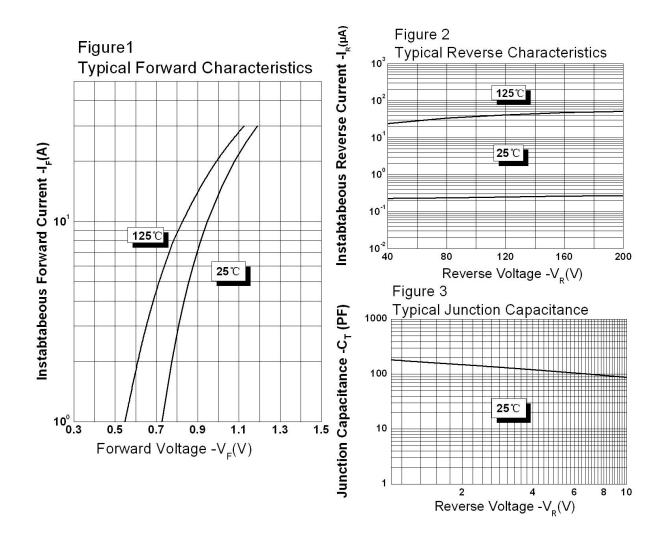




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R _θ JC	DC operation	3.5	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{ heta JA}$	DC operation	50	°C/W
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			

Ratings and Characteristics Curves



[•] China - Germany - Korea - Singapore - United States •

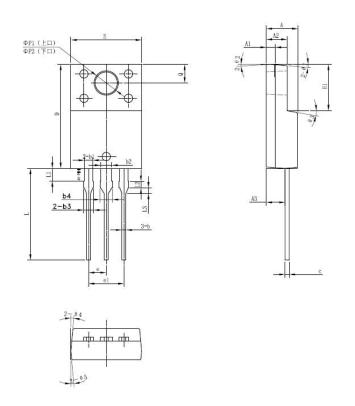
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Mechanical Dimensions ITO-220AB



CVMDOL	Millimeters				
SYMBOL	MIN.	TYP.	MAX.		
Α	4.30	4.50	4.70		
A1	1.10	1.30	1.50		
A2	2.80	3.00	3.20		
A3	2.50	2.70	2.90		
b	0.50	0.60	0.75		
b1	1.10	1.20	1.35		
b2	1.50	1.60	1.75		
b3	1.20	1.30	1.45		
b4	1.60	1.70	1.85		
С	0.50	0.60	0.75		
D	14.80	15.00	15.20		
E	9.96	10.16	10.36		
е		2.55			
e1		5.10			
H1	6.50	6.70	6.90		
L	12.70	13.20	13.70		
L1	1.60	1.80	2.00		
L2	0.80	1.00	1.20		
L3	0.60	0.80	1.00		
ΦP1(上□)	3.30	3.50	3.70		
ΦP2(下口)	2.99	3.19	3.39		
Q	2.50	2.70	2.90		
Θ1		5°			
Θ2		4°			
Θ3		10°			
Θ4		5°			
Θ5		5°			

Tube Specification

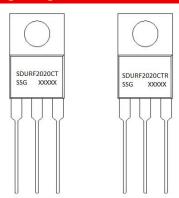


Ordering Information

Device	Package	Shipping
SDURF2020CT(CTR)	ITO-220AB (Pb-Free)	50 pcs/ tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

SDUR = Device Type F = Package type 20 = Forward Current (20A) 20 = Reverse Voltage (200V)

CT(CTR) = Configuration SSG = SSG YY = Year WW = Week

L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

- China Germany Korea Singapore United States
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